# Metal-dielectric hybrid surfaces as integrated optoelectronic interfaces with high optical transmittance and low sheet resistance

Stanford researchers at the Cui Lab have designed a self-aligned hybrid metaldielectric surface that offers unparalleled performance in applications where both a transparent contact and a photon management texture are needed. Current applications include the front surface of solar cells, photodetectors, camera sensors, and LEDs.

The team has developed a prototype of silicon nanopillars protruding through a patterned gold film. Despite high metal coverage (> 60%), this design had extremely high absorption (>97%) and low sheet resistance of 16 Ohm/sq. This design can be easily implemented in multiple metal-semiconductor systems using a simple one-step fabrication process.

#### Video -"Invisible wires' could boost solar-cell efficiency"

**Stanford News**, November 25, 2015 "Stanford engineers develop 'invisible wires' that could improve solar cell efficiency"

#### **Stage of Research**

 Continued research on optimizing and scaling up, developing new catalysts and chemistries, and optimizing optical and electrical properties for different applications.

## Applications

• Any front surface where photon management is required such as at the front surface of solar cells, photodetectors, camera sensors, LEDs, and other optoelectronic devices

## Advantages

- Optimized hybrid optoelectronic interface for maximum performance combines a photon management structure and transparent electrode in one design
- Versatile can be used for any surface
- Low sheet resistance significantly lower sheet resistance values than any technology currently available
- Very efficient up to 97% absorption across 400-900nm light
- Easy to implement
- Simple, one-step fabrication process based on metal-assisted chemical etching (MACE)
- Many different metal and materials stacks possible
  - Silver, gold, copper, aluminum, platinum, palladium, rhodium
  - $\circ\,$  Si, GaAs, InP explored thus far

## **Publications**

 V. K. Narasimhan, T. M. Hymel, R. A. Lai, and Y. Cui. <u>"Hybrid</u> <u>Metal-Semiconductor Nanostructure for Ultrahigh Optical Absorption and Low</u> <u>Electrical Resistance at Optoelectronic Interfaces,"</u> ACS Nano ASAP, 2015

#### Patents

- Published Application: 20160322517
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